

RJK1535DPJ, RJK1535DPE, RJK1535DPF

Silicon N Channel MOS FET
High Speed Power Switching

REJ03G0479-0300

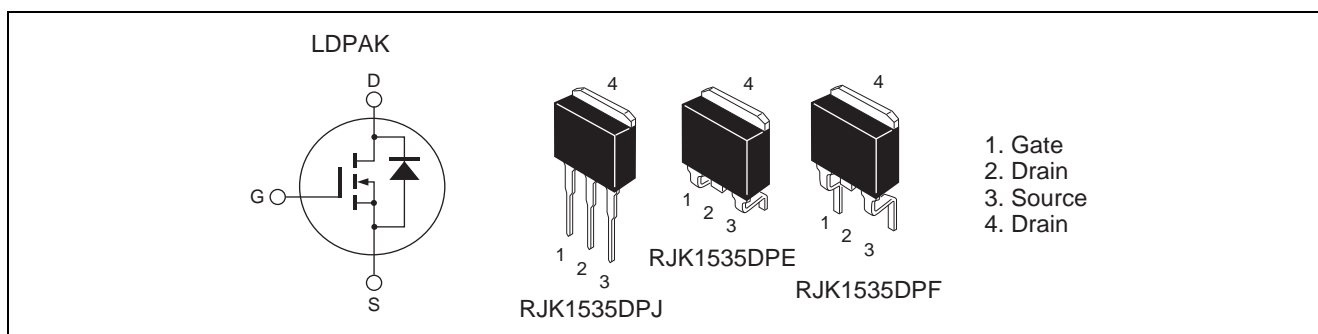
Rev.3.00

Jun 30, 2010

Features

- Low on-resistance
- Low leakage current
- High speed switching

Outline



Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to Source voltage	V _{DSS}	150	V
Gate to Source voltage	V _{GSS}	±30	V
Drain current	I _D	40	A
Drain peak current	I _{D (pulse)} ^{Note1}	100	A
Body-Drain diode reverse Drain current	I _{DR}	40	A
Body-Drain diode reverse Drain peak current	I _{DR (pulse)} ^{Note1}	100	A
Avalanche current	I _{AP} ^{Note3}	30	A
Avalanche energy	E _{AR} ^{Note3}	67.5	mJ
Channel dissipation	P _{ch} ^{Note2}	100	W
Channel to case thermal impedance	θ _{ch-c}	1.25	°C/W
Channel temperature	T _{ch}	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

Notes: 1. PW ≤ 10 μs, duty cycle ≤ 1%

2. Value at Tc = 25°C

3. STch = 25°C, Tch ≤ 150°C

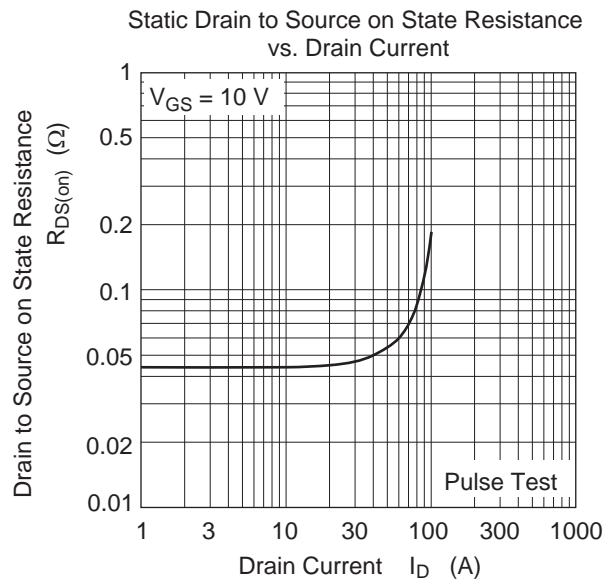
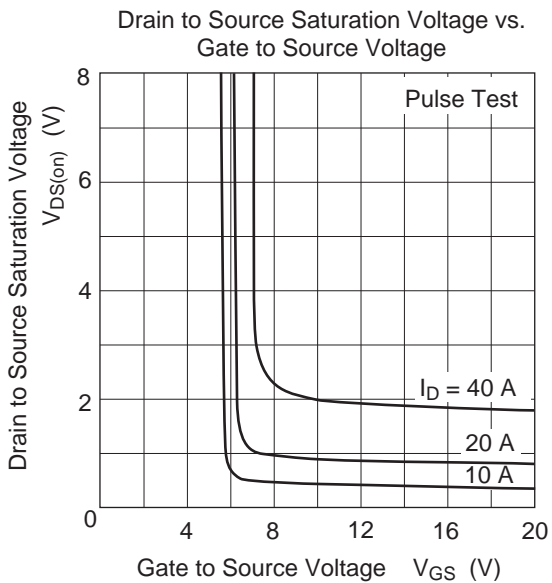
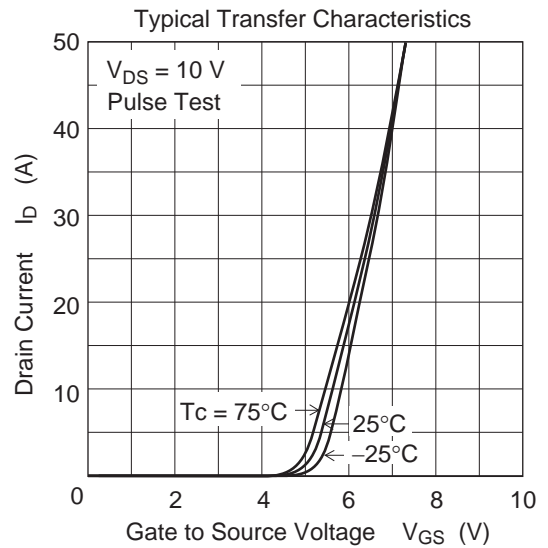
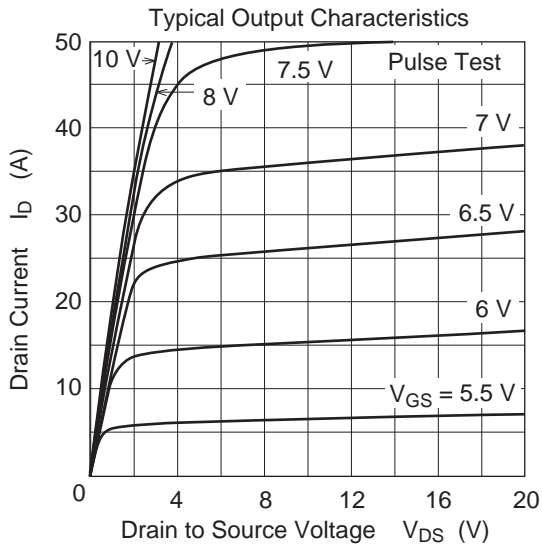
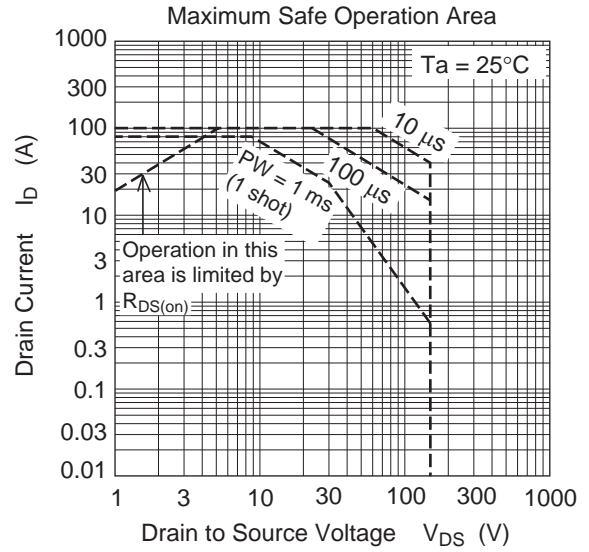
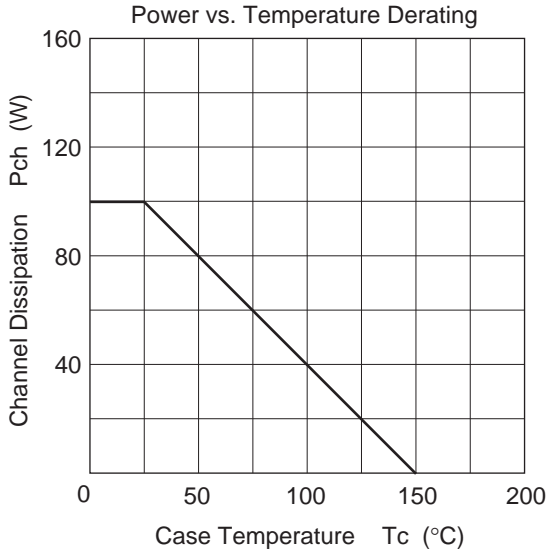
Electrical Characteristics

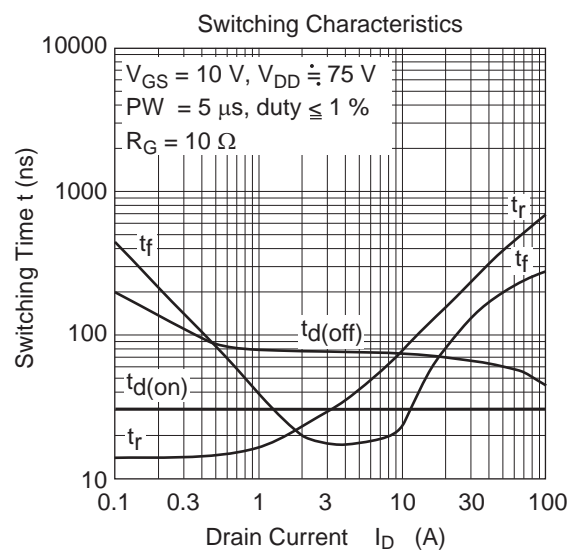
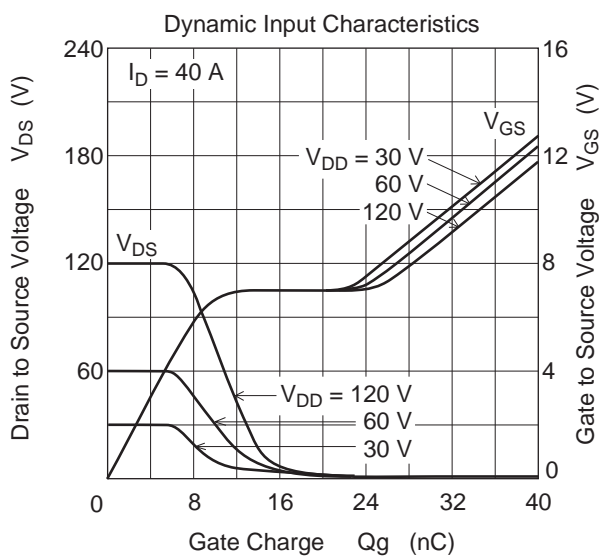
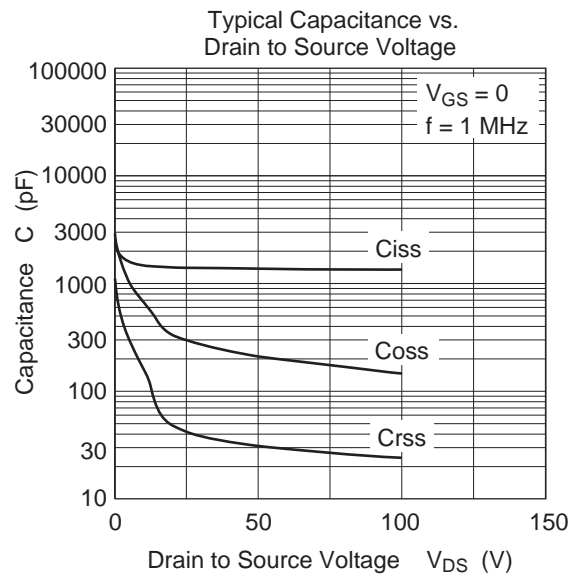
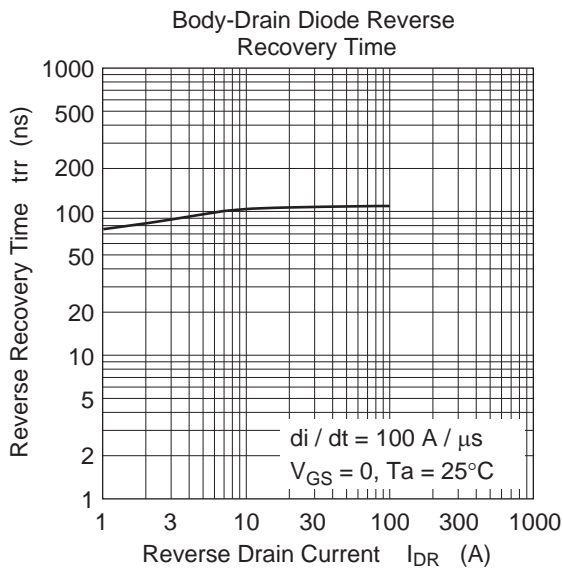
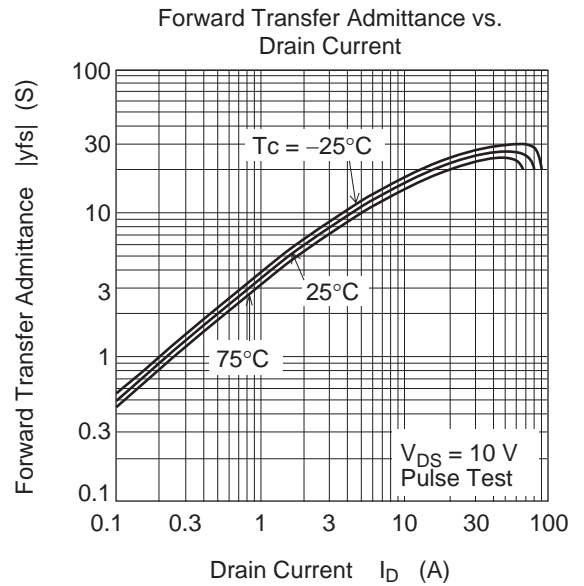
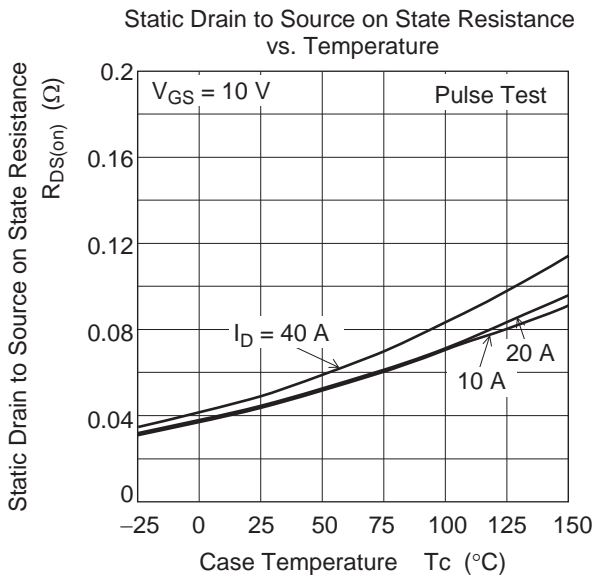
(Ta = 25°C)

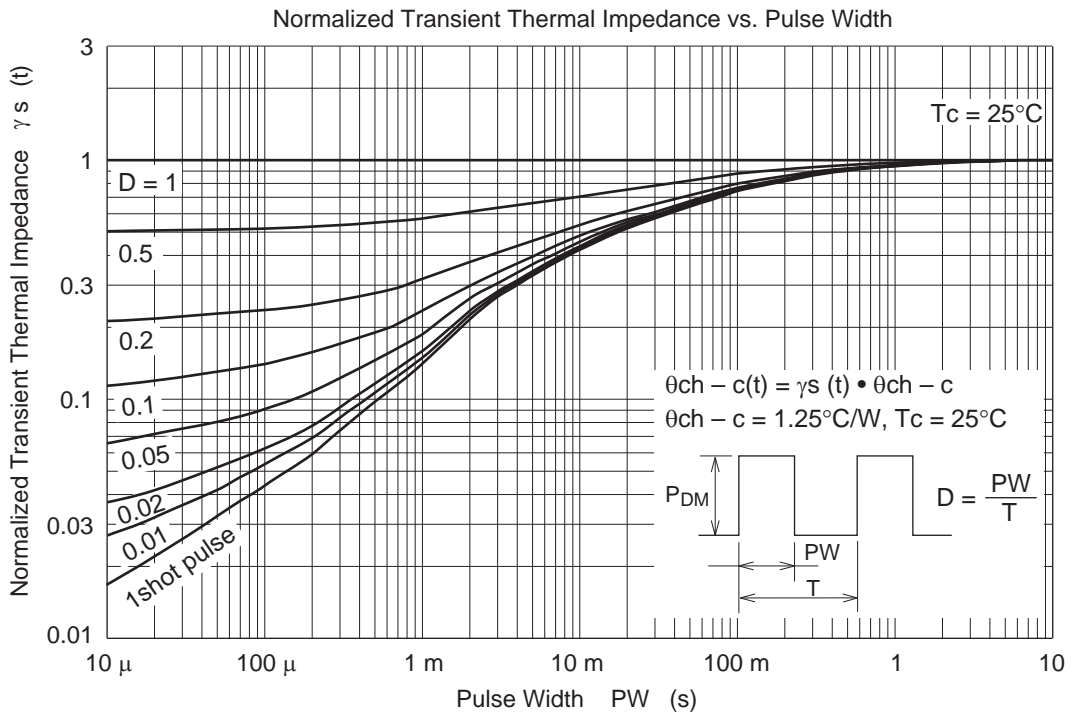
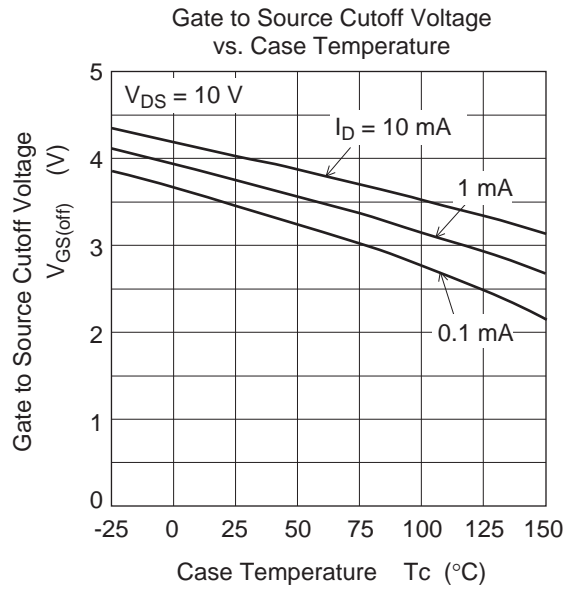
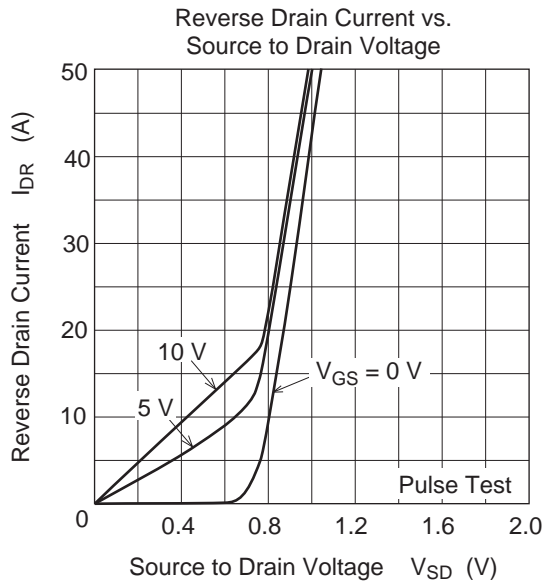
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to Source breakdown voltage	$V_{(BR)DSS}$	150	—	—	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
Zero Gate voltage drain current	I_{DSS}	—	—	1	μA	$V_{DS} = 150 \text{ V}$, $V_{GS} = 0$
Gate to Source leak current	I_{GSS}	—	—	± 0.1	μA	$V_{GS} = \pm 30 \text{ V}$, $V_{DS} = 0$
Gate to Source cutoff voltage	$V_{GS(off)}$	3.0	—	4.5	V	$V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$
Forward transfer admittance	$ y_{fs} $	13	22	—	S	$I_D = 20 \text{ A}$, $V_{DS} = 10 \text{ V}$ ^{Note4}
Static Drain to Source on state resistance	$R_{DS(on)}$	—	0.045	0.052	Ω	$I_D = 20 \text{ A}$, $V_{GS} = 10 \text{ V}$ ^{Note4}
Input capacitance	C_{iss}	—	1420	—	pF	$V_{DS} = 25 \text{ V}$ $V_{GS} = 0$ $f = 1 \text{ MHz}$
Output capacitance	C_{oss}	—	300	—	pF	
Reverse transfer capacitance	C_{rss}	—	42	—	pF	
Turn-on delay time	$t_{d(on)}$	—	30	—	ns	$I_D = 20 \text{ A}$ $V_{GS} = 10 \text{ V}$ $R_L = 3.75 \Omega$ $R_g = 10 \Omega$
Rise time	t_r	—	170	—	ns	
Turn-off delay time	$t_{d(off)}$	—	70	—	ns	
Fall time	t_f	—	80	—	ns	
Total Gate charge	Q_g	—	35	—	nC	$V_{DD} = 120 \text{ V}$ $V_{GS} = 10 \text{ V}$ $I_D = 40 \text{ A}$
Gate to Source charge	Q_{gs}	—	9	—	nC	
Gate to Drain charge	Q_{gd}	—	16	—	nC	
Body-Drain diode forward voltage	V_{DF}	—	1.0	1.5	V	$I_F = 40 \text{ A}$, $V_{GS} = 0$ ^{Note4}
Body-Drain diode reverse recovery time	t_{rr}	—	110	—	ns	$I_F = 40 \text{ A}$, $V_{GS} = 0$ $diF/dt = 100 \text{ A}/\mu\text{s}$
Body-Drain diode reverse recovery charge	Q_{rr}	—	0.5	—	μC	

Notes: 4. Pulse test

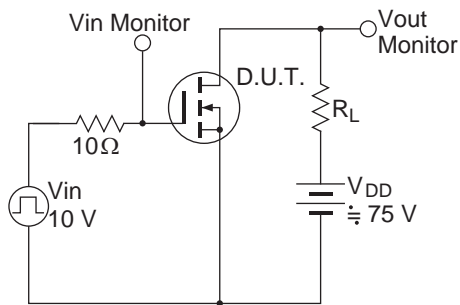
Main Characteristics



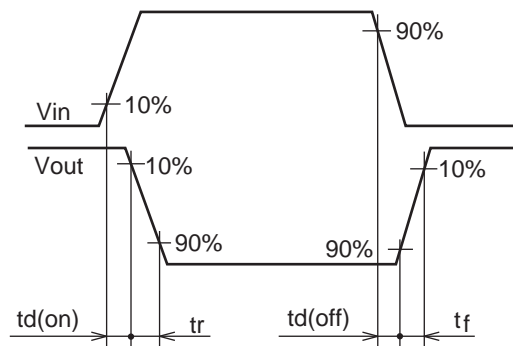




Switching Time Test Circuit

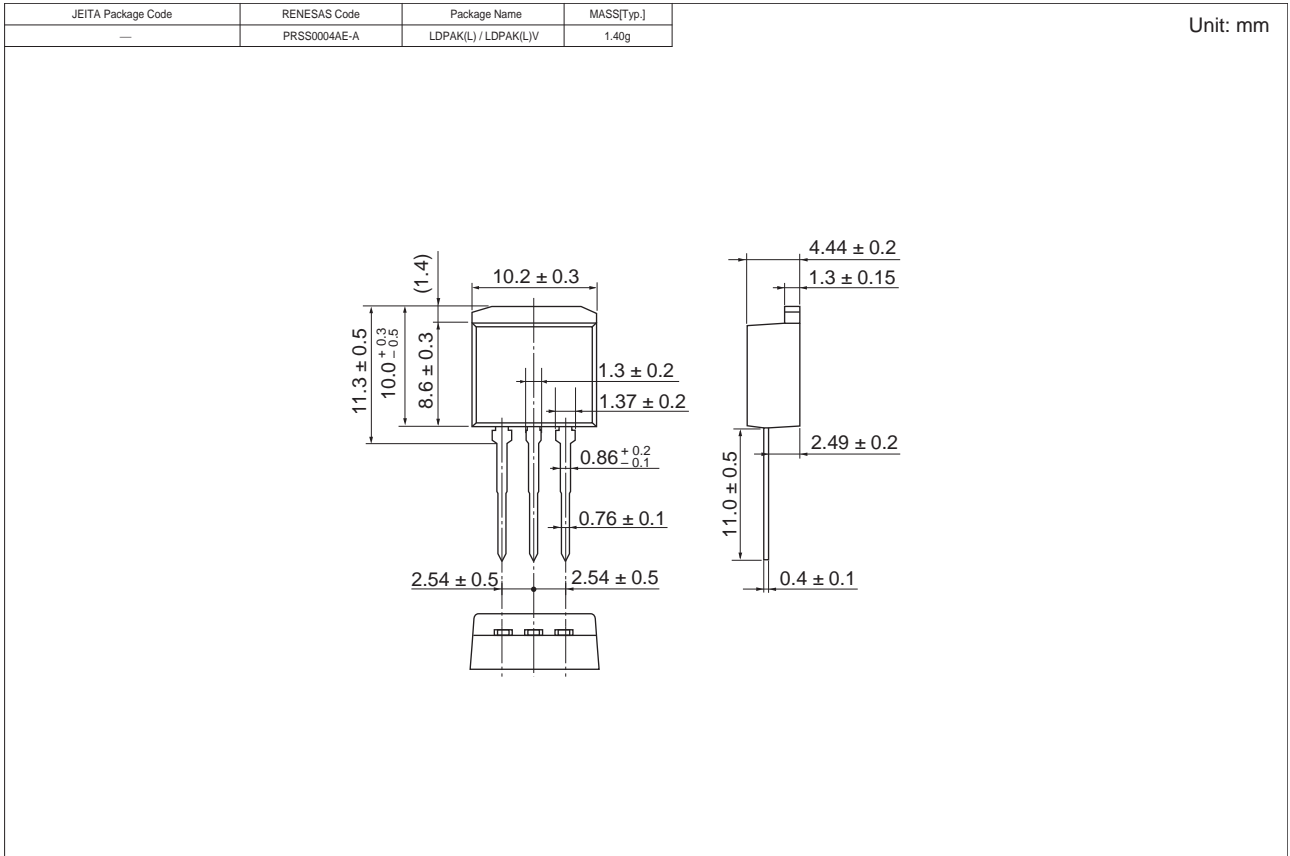


Waveform

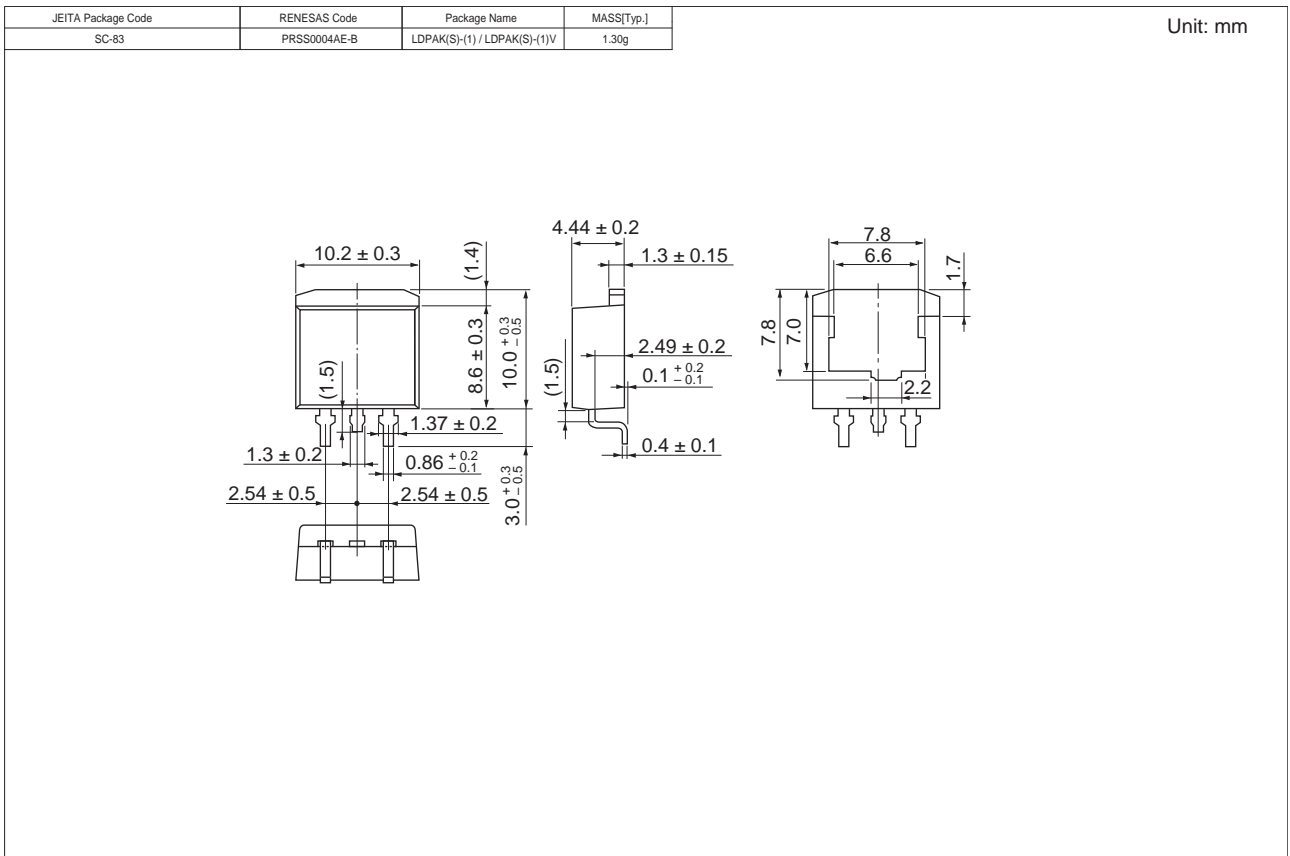


Package Dimensions

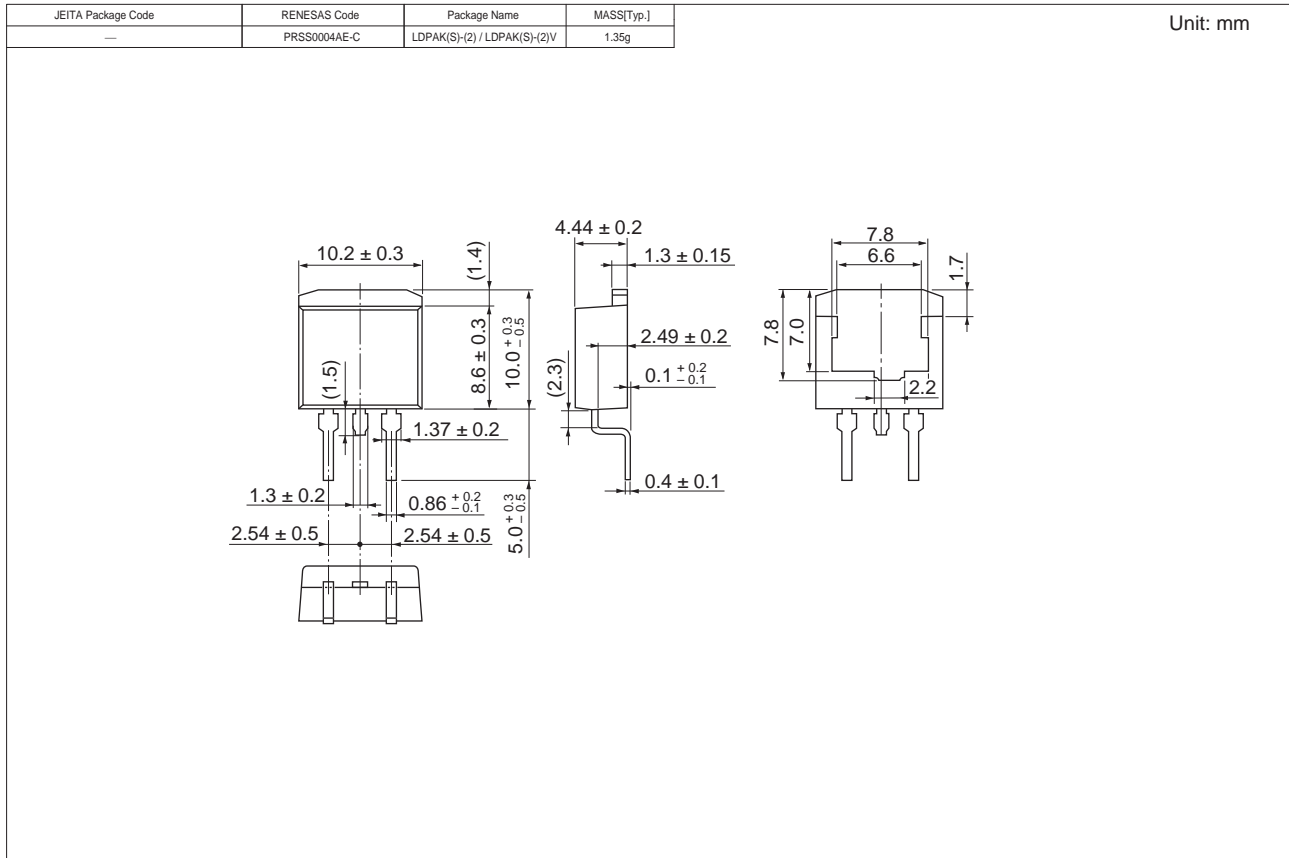
• RJK1535DPJ



• RJK1535DPE



• RJK1535DPF



Ordering Information

Part Name	Quantity	Shipping Container
RJK1535DPE-LE	1000 pcs	Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A.
Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited
1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada
Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 Zhichunlu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China
Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2886-9318, Fax: +852-2886-9022/9044

Renesas Electronics Taiwan Co., Ltd.
7F, No. 363 Fu Shing North Road Taipei, Taiwan
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Renesas Electronics Malaysia Sdn.Bhd.
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Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd.
11F., Samik Laviel'or Bldg., 720-2 Yeoksam-Dong, Kangnam-Ku, Seoul 135-080, Korea
Tel: +82-2-558-3737, Fax: +82-2-558-5141